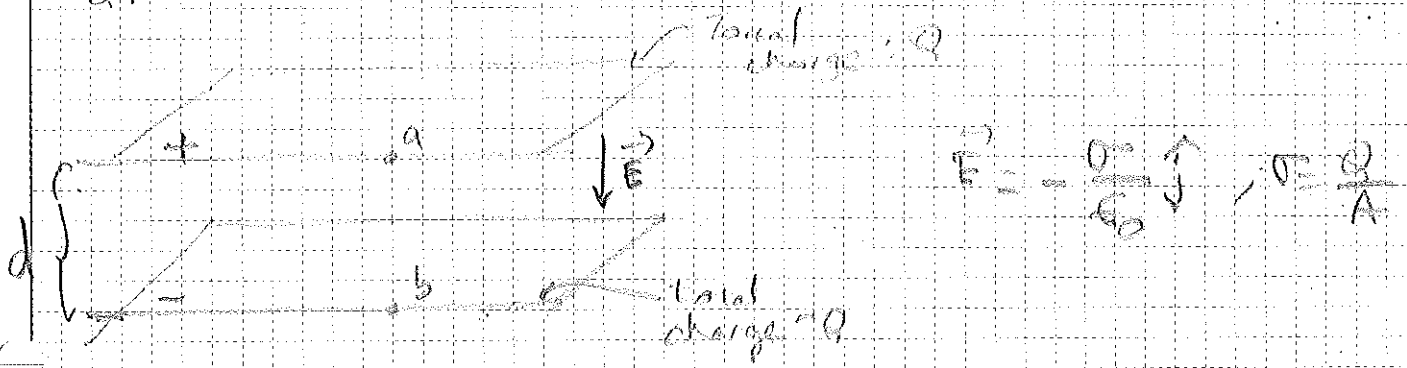


Chapter 26: Capacitance and Dielectrics

Consider parallel conducting plates each having charge $+Q$ and $-Q$.



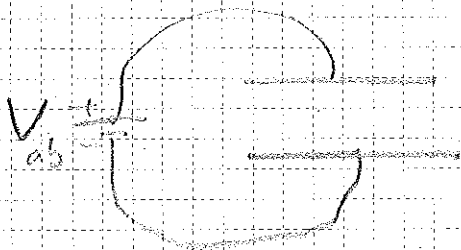
$\rightarrow V_{ab}$: potential difference between the positively charged plate and negatively charged plate is:

$$V_{ab} = \frac{\int_a^b \rho_0 E dy}{\rho_0} = \frac{1}{\rho_0} \int_a^b \rho_0 E dy = -E (y_b - y_a) = \boxed{E d}$$

$$V_{ab} = \frac{\sigma}{\epsilon_0} d = \frac{Q}{A \epsilon_0} d = \frac{Q}{\left(\frac{A \epsilon_0}{d}\right)}$$

← The total charge in the plates.

Now consider charging of the capacitor:

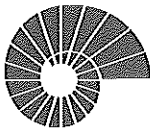


If a voltage V_{ab} is applied total charge $+Q$ and $-Q$ will be generated in plates.

$$\left. \begin{matrix} \text{for } A \uparrow \text{ larger } Q \\ d \downarrow \text{ '' } Q \end{matrix} \right\} \epsilon_0 \frac{A}{d}$$

$\rightarrow \frac{\epsilon_0 A}{d}$ describes the ability of the parallel plates to store charge.

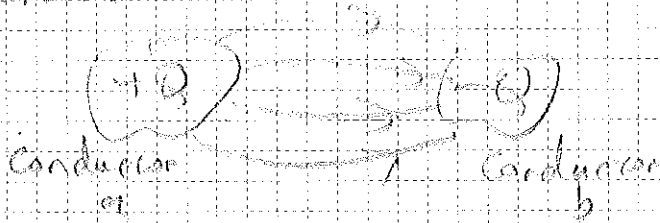
This is called the capacitance $\left[C = \frac{Q}{V_{ab}} \right]$



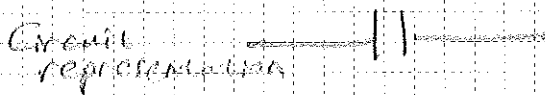
$C = \frac{Q}{V_{ab}}$ a V_{ab} : potential difference between the positively and negatively charged plates.

$+Q$ is the charge stored in $+$ ly charged plate.

In general, any ^{two} conductors separated by an insulator form a capacitor.



$C = \frac{Q}{V_{ab}}$ Capacitance



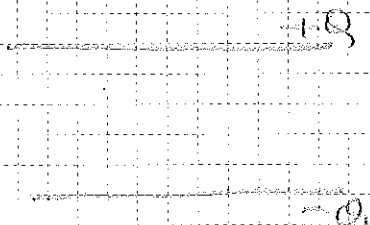
$C = \frac{Q}{V_{ab}}$
(Farad) (Coulomb) / (Volt)

Calculating Capacitance in Vacuum

Approach: Give a two conductors assume a charge $+Q$ on one and $-Q$ on the other conductor. And calculate V_{ab} , potential difference between the $+$ and $-$ charged conductor.

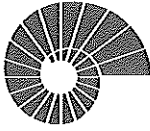
$\therefore C = \frac{Q}{V_{ab}}$

Parallel Plate Capacitor

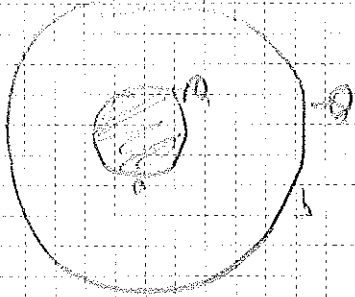


$V_{ab} = Ed = \frac{Q}{\epsilon_0} \frac{d}{A}$

$\therefore C = \frac{\epsilon_0 A}{d} \leftarrow = \frac{QA}{\epsilon_0 d}$



Ex 2.3: Spherical Capacitor



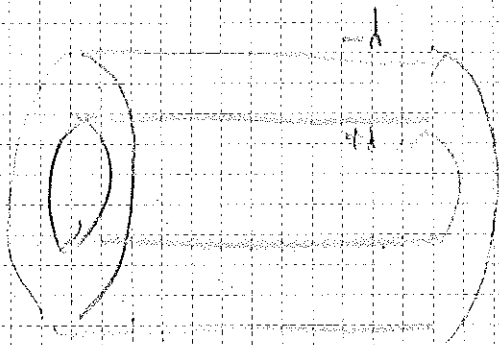
Capacitance of two concentric spherical conducting shells.

$$V_{ab} = \int_a^b E \cdot dr = \int_a^b \frac{1}{4\pi\epsilon_0} \cdot \frac{Q}{r^2} dr$$

$$= \frac{Q}{4\pi\epsilon_0} \left[-\frac{1}{r} \right]_a^b = \frac{Q}{4\pi\epsilon_0} \left(\frac{1}{r_a} - \frac{1}{r_b} \right)$$

$$\Rightarrow C = \frac{Q}{V_{ab}} = \frac{4\pi\epsilon_0}{\frac{1}{r_a} - \frac{1}{r_b}} = \frac{4\pi\epsilon_0 r_a r_b}{r_b - r_a}$$

Ex 2.4: Cylindrical Capacitor



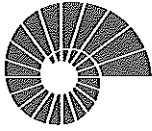
Long cylinder, linear charge density λ surrounded by cylindrical shell.
What is the capacitance per unit length?

Consider a portion with length L :

$$2\pi r E L = \frac{Q}{\epsilon_0} \Rightarrow E(r) = \frac{\lambda}{2\pi\epsilon_0 r}$$

$$\Rightarrow V_{ab} = \int_a^b \frac{\lambda}{2\pi\epsilon_0 r} dr = \frac{\lambda}{2\pi\epsilon_0} \ln\left(\frac{r_b}{r_a}\right) \Rightarrow C = \frac{Q}{V_{ab}} = \frac{2\pi\epsilon_0 L}{\ln\left(\frac{r_b}{r_a}\right)}$$

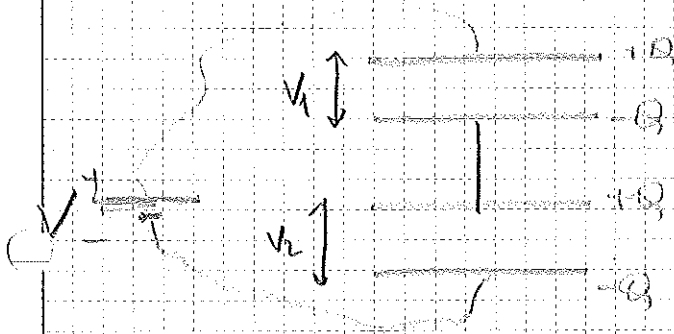
$$\Rightarrow C = \frac{2\pi\epsilon_0 L}{\ln\left(\frac{r_b}{r_a}\right)} \Rightarrow \text{Capacitance per unit length: } \frac{C}{L} = \frac{2\pi\epsilon_0}{\ln\left(\frac{r_b}{r_a}\right)}$$



Capacitors in Series and Parallel

Capacitors in series

Suppose you have two



parallel plate capacitors initially uncharged.

The capacitors are serially interconnected.

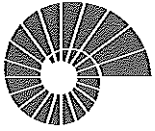
When a potential difference V is applied to this system the plates will be charged such that they have the same magnitude of charge.

$$\Rightarrow V = V_1 + V_2 = \frac{Q}{C_1} + \frac{Q}{C_2} \Rightarrow V = Q \left(\frac{1}{C_1} + \frac{1}{C_2} \right) = \frac{Q}{C_{eq}}$$

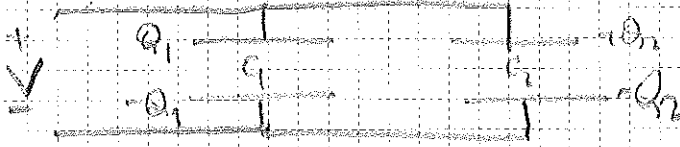
$$\boxed{\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2}}$$

For capacitors in series

$$\boxed{\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2} + \dots}$$



Capacitors in Parallel



In a parallel connection the potential difference of all individual capacitors is the same.

$$\Rightarrow V = \frac{Q_1}{C_1}, \quad V = \frac{Q_2}{C_2}$$

Total charge stored in the capacitors

$$Q = Q_1 + Q_2$$

$$\Rightarrow Q = V(C_1 + C_2)$$

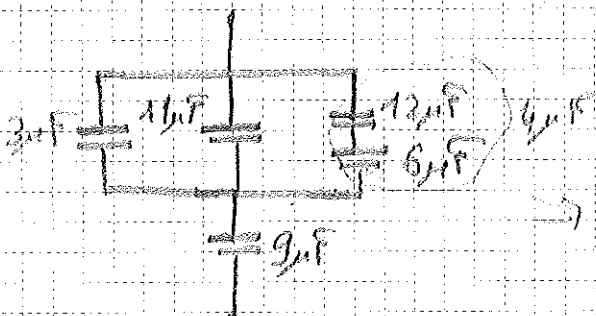
$$\Rightarrow (C_1 + C_2) = \frac{Q}{V} = C_{eq}$$

$$\Rightarrow \boxed{C_{eq} = C_1 + C_2}$$

For many capacitors in parallel:

$$\boxed{C_{eq} = C_1 + C_2 + \dots}$$

Ex 24.6: A capacitor network

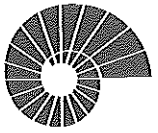


Solve the problem in pieces.

$$\frac{1}{6\mu F} + \frac{1}{12\mu F} = \frac{1}{4\mu F}$$

$$\frac{1}{9\mu F} + \frac{1}{4\mu F} = \frac{1}{6\mu F}$$

$$\frac{1}{9\mu F}$$



$$V_{ab} = V_a - V_b = \int_a^b \vec{E} \cdot d\vec{l}, \quad W_{ab} = U_a - U_b = V_a - V_b$$

24.3 Energy Storage in Capacitors and Electric-Field Energy

The work required to charge a capacitor gives the potential energy stored in the capacitor.

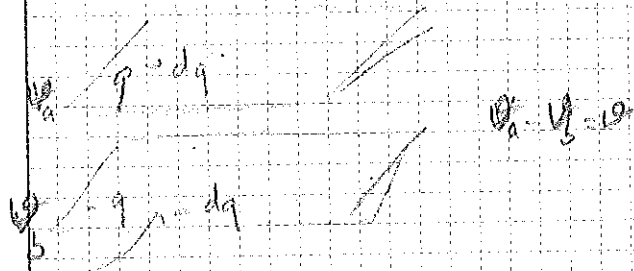
Suppose the final voltage of the capacitor is V .

$$V = \frac{Q}{C}$$

At an intermediate stage: $Q = \frac{q}{C}$

Work done ^{by the external force} to add a charge dq to the capacitor:

$$dW = dq(V_a - 0) + (-dq)(V_b - 0) = dq(V_a - V_b) = dqV$$



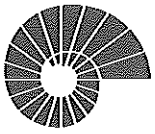
$$\begin{aligned} W &= \int dW = \int dqV \\ &= \int \frac{q}{C} dq = \frac{1}{C} \frac{Q^2}{2} = \boxed{\frac{Q^2}{2C}} \end{aligned}$$

work done in charging a capacitor

W will also describe the total work done by the electric field when the capacitor discharges.

If we define the potential energy of an uncharged capacitor to be equal to 0, then

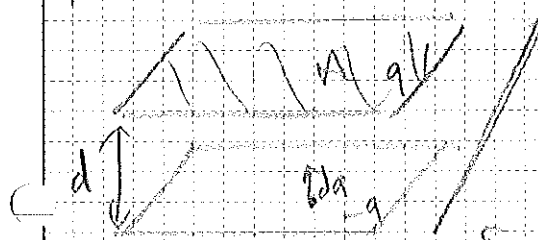
$$\begin{aligned} U &= \frac{Q^2}{2C}, \text{ potential energy of the charged capacitor.} \\ &= \frac{1}{2} CV^2 = \frac{1}{2} QV \end{aligned}$$



Electric-Field Energy

We can also imagine charging of a capacitor by moving electrons from one plate to another.

In this case energy is stored in the field between the plates.



Energy density:
 $u = \frac{\frac{1}{2} CV^2}{Ad}$

For parallel plates:

$C = \epsilon_0 \frac{A}{d}, V = Ed$

$u = \frac{1}{2} \frac{\epsilon_0 \frac{A}{d} E^2 d}{Ad} = \frac{1}{2} \epsilon_0 E^2$

This expression for energy density is valid for any electric field configuration in vacuum.

$dW_{ext} = dq(V_+ - V_-)$
 $= -dqV_+$

$dW_{ext} = dqV_+$
 $W_{ext} = \frac{1}{2} CV^2$

Ex. 24.7:



C_1 is charged by connecting to a source of potential difference $V_0 = 120V$. Once C_1 is charged the source of potential difference is disconnected.

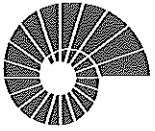
a) What is the charge Q_0 if the switch S is left open.

$Q_0 = C_1 V_0 = (8 \mu F)(120V) = 960 \mu C$

b) Energy stored in C_1 if S is open

$\frac{1}{2} C_1 V_0^2 = \frac{1}{2} (8 \mu F)(120V)^2 = 0.058J$

c) S is closed \rightarrow What is the potential difference across each capacitor, charge across each capacitor?



Total charge will be conserved

$$\Rightarrow Q_0 = Q_1 + Q_2 = C_1 V + C_2 V = (C_1 + C_2) V$$

$$V_1 = V_2 \rightarrow$$

$$\Rightarrow 260 \mu\text{C} = (8 \mu\text{F} + 4 \mu\text{F}) V \Rightarrow \boxed{V = 80\text{V}}$$

$$Q_1 = C_1 V = 8 \mu\text{F} \cdot 80\text{V} = 640 \mu\text{C}$$

$$Q_2 = C_2 V = 4 \mu\text{F} \cdot 80\text{V} = 320 \mu\text{C}$$

d) Total energy of the system after S is closed:

$$U_1 = \frac{1}{2} C_1 V^2$$

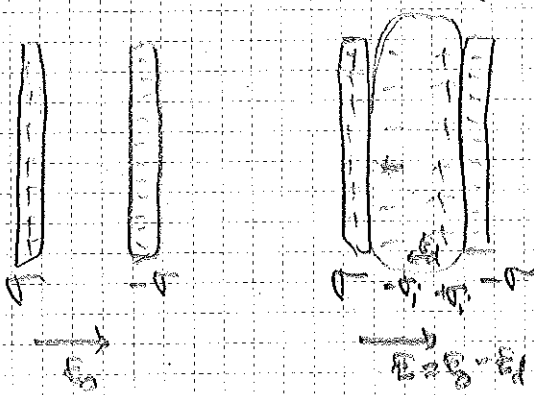
$$U_2 = \frac{1}{2} C_2 V^2$$

$$\} \Rightarrow U = \frac{1}{2} (8 \mu\text{F} + 4 \mu\text{F}) (80\text{V})^2 = \boxed{0.038\text{J}} \quad \left(\frac{0.058\text{J}}{2} \right)$$

Energy lost during charging of the capacitors

24.4 Dielectrics: Insulating (non-conducting) materials placed in capacitors.

Consider parallel conducting plates

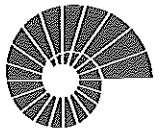


When a dielectric material is placed between the parallel plates, surface charges are induced in the dielectric.
"Polarization"

Induced surface charges cause a decrease in the electric field intensity between the parallel plates.

$$E = \frac{E_0}{k} \} \text{decreased electric field intensity compared to vacuum}$$

↑
dielectric constant



Conductor / Dielectric
 $\sigma = \sigma_f$

without the dielectric:

$$E_0 = \frac{\sigma}{\epsilon_0}$$

with dielectric: $E = \frac{\sigma}{\epsilon} = \frac{\sigma}{k\epsilon_0}$

$$\frac{\sigma_f}{k\epsilon_0} = \frac{\sigma - \sigma_i}{\epsilon_0}$$

induced charge density

Permittivity of the dielectric

$$\sigma_i = \sigma \left(1 - \frac{1}{k}\right)$$

now $E = \frac{\sigma}{\epsilon}$ \Rightarrow all the formulas for vacuum will be valid for the case of a dielectric when ϵ_0 is substituted with ϵ .

$\Rightarrow C = \epsilon \frac{A}{d}$, capacitance of parallel plates

$u = \frac{1}{2} \epsilon E^2$, energy density.

Gauss's Law in Dielectrics:

Gauss's Law is modified in dielectrics as:

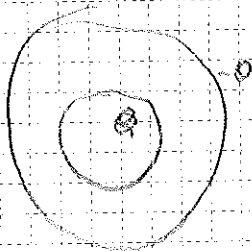
$$\oint \vec{E} \cdot d\vec{A} = \frac{Q - Q_i}{\epsilon_0} = \frac{Q_{\text{enc, free}}}{k\epsilon_0}$$

Total free charge enclosed by the Gaussian surface

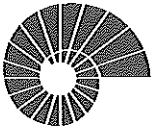
Ex 24.12: Spherical capacitor with dielectric:

If the volume between spherical shells is filled with oil (dielectric constant k), what is the capacitance?

According to Gauss's Law:

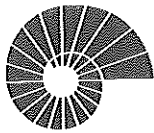


$$\oint k\vec{E} \cdot d\vec{A} = k \epsilon_0 \oint \vec{E} \cdot d\vec{A} = \frac{Q}{\epsilon_0} \Rightarrow E(r) = \frac{1}{4\pi\epsilon} \frac{Q}{r^2}$$

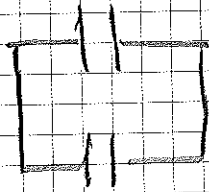


$$E(r) = \frac{1}{4\pi\epsilon} \frac{Q}{r^2} \Rightarrow V_{a \rightarrow b} = \int_a^b \frac{1}{4\pi\epsilon} \frac{Q}{r^2} dr$$
$$= \int_{r_a}^{r_b} \frac{1}{4\pi\epsilon} \frac{Q}{r^2} dr = \frac{1}{4\pi\epsilon} Q \left(\frac{1}{r_a} - \frac{1}{r_b} \right)$$

$$\Rightarrow C = \frac{Q}{V} = \frac{4\pi\epsilon}{r_b - r_a} r_a r_b //$$



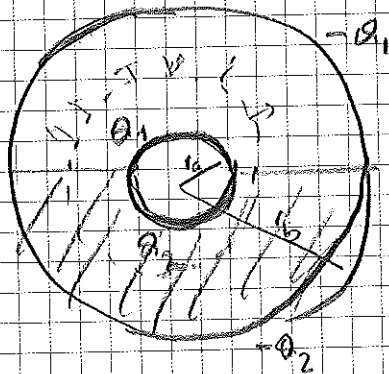
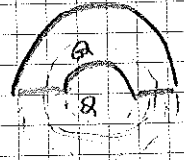
Parallel connection



remember: $C = \frac{4\pi\epsilon_0 r_a r_b}{r_b - r_a} = \frac{Q}{V}$

for a full sphere

for a half sphere: $C = \frac{Q}{2V}$



$$C_1 = \frac{4\pi\epsilon_0}{2} \frac{r_a r_b}{r_b - r_a} = \frac{Q_1}{V}$$

$$C_2 = \frac{4\pi k\epsilon_0}{2} \frac{r_a r_b}{r_b - r_a} = \frac{Q_2}{V}$$

$$C_{eq} = 2\pi\epsilon_0 \left(\frac{a b}{r_b - r_a} \right) (1+k)$$

b) $\oint \vec{E} \cdot d\vec{a} = \frac{Q_{free}}{K\epsilon_0}$, use a hemispherical Gaussian surface

for the upper: $E \frac{4\pi r^2}{2} = \frac{Q_1}{\epsilon_0} \Rightarrow E = \frac{1}{2\pi\epsilon_0} \frac{Q_1}{r^2}$, $\frac{Q_2}{K} = Q_1$, $Q_1 + Q_2 = Q \Rightarrow Q_1 + KQ_1 = Q$

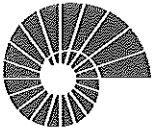
lower: $E \frac{4\pi r^2}{2} = \frac{Q_2}{K\epsilon_0} \Rightarrow E = \frac{1}{2\pi K\epsilon_0} \frac{Q_2}{r^2}$

$$\Rightarrow E = \frac{1}{2\pi\epsilon_0} \frac{Q}{(1+K)r^2}$$

same for upper and lower halves

$$c) \sigma_u = \frac{Q_1}{2\pi r_a^2} = \frac{Q}{2\pi r_a^2 (1+K)}, \quad \sigma_L = \frac{Q}{2\pi r_b^2 (1+K)}$$

$$\sigma_L = \frac{Q_2}{2\pi r_a^2} = \frac{KQ}{2\pi r_a^2 (1+K)}, \quad \sigma_L = \frac{KQ}{2\pi r_b^2 (1+K)}$$



d) Upper plate: $\sigma_{\text{bound } u} = 0$

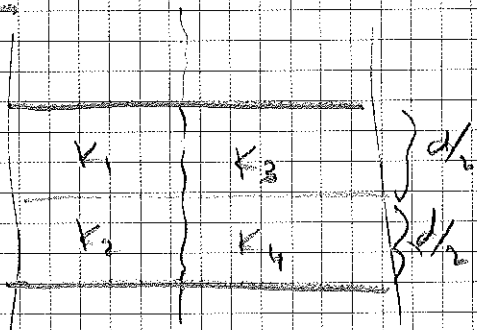
Lower plate: $\sigma_{i,u} = \sigma_{\text{free}} \left(1 - \frac{1}{k}\right)$

$$= \frac{Q}{2\pi r_a^2} \cdot \frac{1}{(k+1)} \cdot \left(\frac{k-1}{k}\right) = \frac{Q}{2\pi r_a^2} \left(\frac{k-1}{k+1}\right)$$

$$\text{on } r_b \quad \sigma_{i,l} = \frac{Q}{2\pi r_b^2} \left(\frac{k-1}{k+1}\right)$$

e) zero bound charge on the flat surface of the interface.

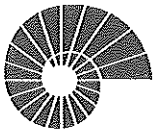
E_u



$$C_{12} = \frac{2A\epsilon_0}{2d} \left(\frac{k_1 k_2}{k_1 + k_2}\right)$$

$$C_{34} = \frac{2A}{2} \frac{\epsilon_0}{d} \left(\frac{k_3 k_4}{k_3 + k_4}\right)$$

$$\rightarrow C_{\text{eq}} = C_{12} + C_{34} = \frac{A\epsilon_0}{d} \left\{ \frac{k_1 k_2}{k_1 + k_2} + \frac{k_3 k_4}{k_3 + k_4} \right\}$$



M71 Review:

Chap. 21: Electric Charge and Electric Field



$$|\vec{F}| = \frac{1}{4\pi\epsilon_0} \frac{q_1 q_2}{r^2}$$

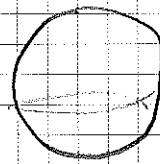
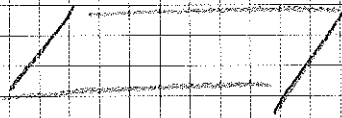


$$\vec{E} = \frac{1}{4\pi\epsilon_0} \frac{q}{r^2} \hat{r}$$



Chap. 22: Gauss' Law

$$\oint \vec{E} \cdot d\vec{\tau} = \frac{Q_{enc}}{\epsilon}$$



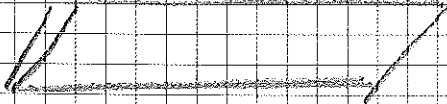
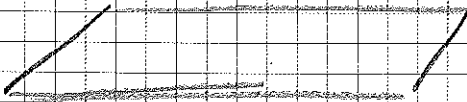
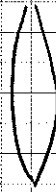
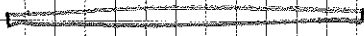
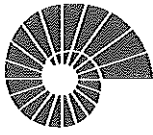
Chap. 23: Electric Potential Energy

$$\int_a^b \vec{F}_e \cdot d\vec{\ell} = U_a - U_b$$

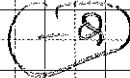
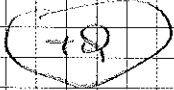
$$V_a - V_b = \int_a^b \vec{E} \cdot d\vec{\ell}$$



$$V = \frac{1}{4\pi\epsilon_0} \int \frac{dq}{r}$$



Chap. 24: Capacitance and Dielectrics

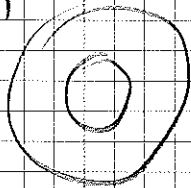


Capacitance calculations, - Assume charges $+Q$ and $-Q$

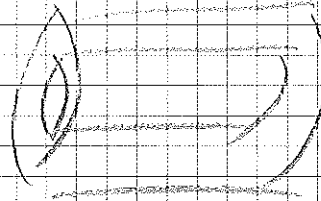
- Calculate V

- Find $C = \frac{Q}{V}$

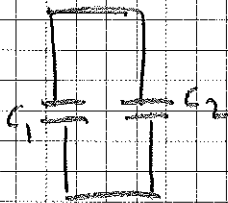
spherical
cap



Cylindrical
cap



same Q

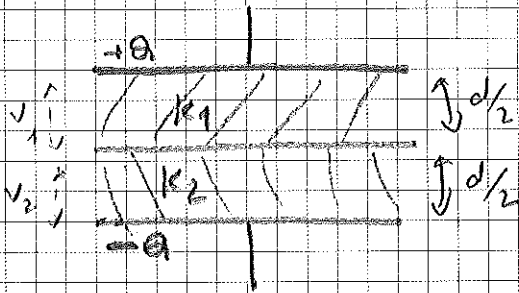


same V

Energy storage: $E = \frac{Q^2}{2C} = \int \nu dq = \int \frac{q}{C} dq = \frac{Q^2}{2C}$



Prob 24.71:



Parallel plate capacitor, space between the plates filled with two slabs of dielectric. Each slab has thickness $d/2$.

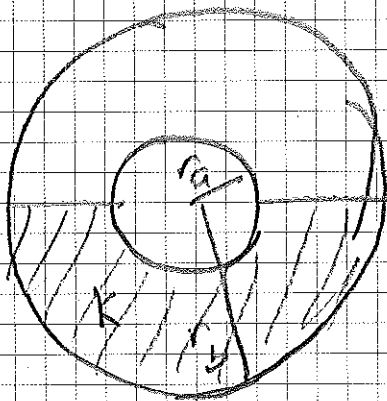
Show that $C = \frac{2\epsilon_0 A}{d} \left(\frac{K_1 K_2}{K_1 + K_2} \right)$



$$C_1 = \frac{2K_1 A \epsilon_0}{d}, \quad C_2 = \frac{2K_2 A \epsilon_0}{d}$$

$$C_{eq} = \frac{C_1 C_2}{C_1 + C_2} = \frac{2A \epsilon_0}{d} \left(\frac{K_1 K_2}{K_1 + K_2} \right)$$

Prob 24.78:



Spherical capacitor,

Half of the volume between two conductors is filled with a liquid dielectric of constant K .

a) Capacitance of the half filled capacitor

b) Magnitude of \vec{E} in the volume between the two conductors, for both the upper and lower halves

c) Surface density of free charges on the upper and lower halves of the inner and outer conductors.

d) Surface density of bound charge at $r = a$, and $r = b$.

e) Surface density of bound charge on the flat surface of the dielectric?